

FUNDAMENTALS OF MICRO AND NANOFABRICATION

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PRE-REQUISITES: General background in Physics, Chemistry, Materials, Chemical engineering, Mechanical engineering, or Electronic engineering should be enough.

INTENDED AUDIENCE: Masters students interested in fundamentals of top-down micro and nanodevice fabrication

INDUSTRIES APPLICABLE TO: Electronic Device Manufacturing

COURSE OUTLINE:

The course provides an in-depth understanding of top-down device fabrication. Focus is the unit processes typically used in micro & nanofabrication of devices. Both concepts and practical aspects are covered. Topics include crystal growth, doping, chemical vapor deposition, physical vapor deposition, photolithography, wet etching, dry etching, and packaging. The course is accessible to students from diverse backgrounds, such as materials, physics, chemistry, mechanical engineering, and electrical engineering. The course will be a derivative of NE203: Advanced Micro & Nano Fabrication Technology & Processes. Students from various departments outside CeNSE, e.g. Physics, Chemistry, ECE, DESE, IAP, routinely take the course.

ABOUT INSTRUCTOR:

Prof.Sushobhan has worked in the field of semiconductor device fabrication technology for more than 10 years, specializing on photovoltaics. His PhD thesis was on organic/Si heterojunction silicon solar cells. He then worked as a post-doctoral research associate in the Princeton Institute of Science and Technology of Materials (PRISM), where he worked on oxide/Si heterojunction solar cells. Since 2014, he has been working an assistant professor in the Indian Institute of Science at the Centre for Nano Science and Engineering (CeNSE), Indian Institute of Science (IISc). In 2014, he was awarded Sir Visvesvaraya Young Faculty Research Fellowship by Ministry of Electronics and Information Technology (MeitY), Government of India. In 2018 he was awarded the Young Engineer Award by the Indian National Academy of Engineers (INAE). He is a young associate of the INAE, member of IEEE (Institute of Electrical Electronics Engineers), and member of MRS. Sushobhans current research interests are thin-film photovoltaics, heterojunction solar cells. and metal-oxide electronics. He has authored research papers and holds Taiwanese patent (US and European patent а pending).Sushobhan is a member of the Administration Committee of the National Nanofabrication Facility at CeNSE. He is also a member of the Institute Safety Committee and Safety warden for CeNSE

Prof.Shankar obtained B.E. Kumar Selvaraia Electronics and Communication Engineering Dr. MCET, Pollachi, Bharathiar University, M.E. Optical Communication from College University Engineering, Anna University, Chennai, M. Microelectronics and Microsystems from S. Twente, The Netherlands and Ph.D. in Photonics Engineering from Ghent University, Belgium 2011. His doctoral thesis was carried out at imec (inter-university microelectronics Leuven, Belgium on wafer-scale fabrication technology for Silicon photonic integrated circuits. supported by Dehouse doctoral grant and scientific leadership training award to conduct his doctoral work. Between 2011 and 2014, he worked at imec, Belgium developing next-generation microprocessor for high-speed computing using Silicon photonic integrated circuits. He has spent a decade in the area of silicon photonic developing state-of-the-art process and device technology Complementary-Metal-Oxide-Semiconductor for Silicon (CMOS) compatible photonic integrated optical interconnect. Dr.Shankar Kumar Selvaraja joined Centre circuit for high-speed for Nano of Science and Engineering at Indian Institute Science (IISc) in 2014 as an Assistant Photonics Research Professor, where he is heading the Laboratory. He is currently deputy chairman of the National Nanofabrication Center at IISc. He was awarded Early Career Research Award by Department of Science and Technology-Science and Engineering Research Board (DST-SERB), Government of Indian. In 2014, he was awarded Sir Visvesvaraya Young Faculty Research Fellowship by Ministry of Electronics and Information (MeitY), Government of India. He is а senior member of IEEE (Institute of Electrical Electronics Engineers), Member of OSA (Optical Society of America) and SPIE. His current area includes high-speed Si photonics. Silicon Nitride photonics circuits. microwave photonics. and on-chip mic-IR sensing technology.

COURSE PLAN:

Week 1: Introduction to micro-fabrication

Week 2: Substrate

Week 3: Cleaning

Week 4: Additive processing: Doping

Week 5: Additive processing: Native Films

Week 6: Additive processing: CVD

Week 7: Additive processing: PVD

Week 8: Lithography 1

Week 9: Lithography 2

Week 10: Subtractive Process: Wet Etching

Week 11: Subtractive Process: Dry Etching

Week 12: CMP and Packaging